

DATA SHEET

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74LVT86

3.3V Quad 2-input exclusive-OR gate

Product specification

1996 Sep 10

IC24 Data Handbook

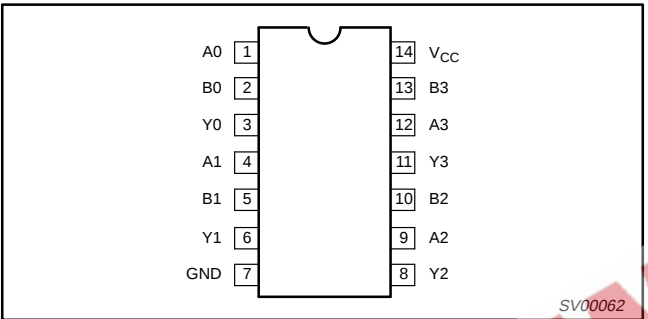
3.3V Quad 2-input exclusive-OR gate

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QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS $T_{amb} = 25^{\circ}\text{C}$; $GND = 0V$	TYPICAL	UNIT
t_{PLH} t_{PHL}	Propagation delay A_n or B_n to Y_n	$C_L = 50\text{pF}$; $V_{CC} = 3.3V$	3.4 3.5	ns
C_{IN}	Input capacitance	$V_I = 0V$ or $3.0V$	3	pF
I_{CCL}	Total supply current	Outputs Low; $V_{CC} = 3.6V$	1	mA

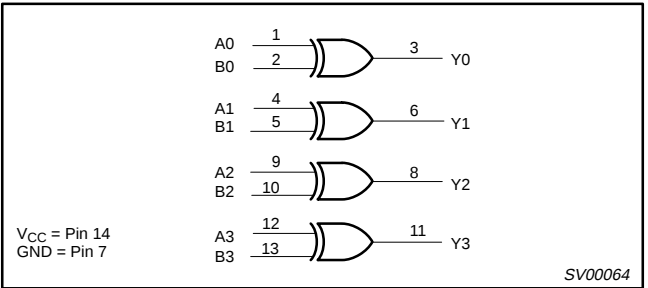
PIN CONFIGURATION



PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 2, 4, 5, 9, 10, 12, 13	A_n, B_n	Data inputs
3, 6, 8, 11	Y_n	Data outputs
7	GND	Ground (0V)
14	V_{CC}	Positive supply voltage

LOGIC DIAGRAM

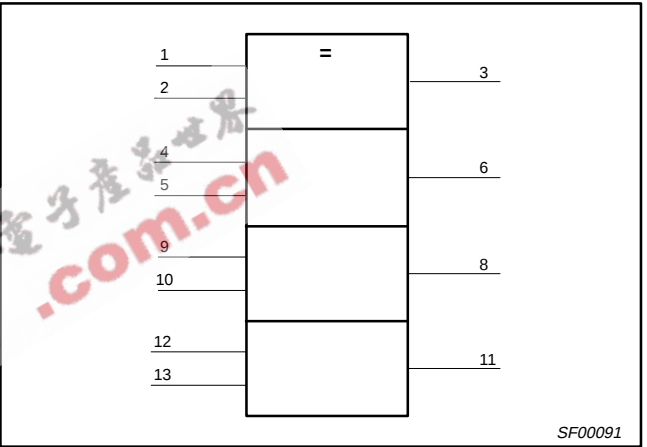


FUNCTION TABLE

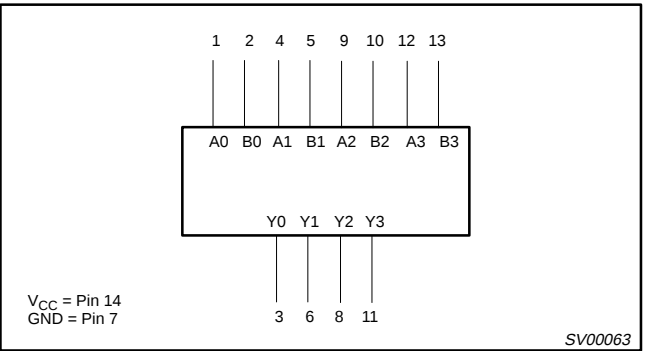
INPUTS		OUTPUT
D_{na}	D_{nb}	Q_n
L	L	L
L	H	H
H	L	H
H	H	L

NOTES:
H = High voltage level
L = Low voltage level

LOGIC SYMBOL (IEEE/IEC)



LOGIC SYMBOL



ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
14-Pin Plastic SO	-40°C to $+85^{\circ}\text{C}$	74LVT86 D	74LVT86 D	SOT108-1
14-Pin Plastic SSOP	-40°C to $+85^{\circ}\text{C}$	74LVT86 DB	74LVT86 DB	SOT337-1
14-Pin Plastic TSSOP	-40°C to $+85^{\circ}\text{C}$	74LVT86 PW	74LVT86PW DH	SOT402-1

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ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V_{CC}	DC supply voltage		−0.5 to +4.6	V
I_{IK}	DC input diode current	$V_I < 0$	−50	mA
V_I	DC input voltage ³		−0.5 to +7.0	V
I_{OK}	DC output diode current	$V_O < 0$	−50	mA
V_{OUT}	DC output voltage ³	Output in Off or High state	−0.5 to +7.0	V
I_{OUT}	DC output current	Output in High state	−32	mA
		Output in Low state	64	
T_{stg}	Storage temperature range		−65 to 150	°C

NOTES:

- Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.
- The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIMITS		UNIT
		MIN	MAX	
V_{CC}	DC supply voltage	2.7	3.6	V
V_I	Input voltage	0	5.5	V
V_{IH}	High-level input voltage	2.0		V
V_{IL}	Low-level Input voltage		0.8	V
I_{OH}	High-level output current		−20	mA
I_{OL}	Low-level output current		32	mA
$\Delta t/\Delta v$	Input transition rise or fall rate; Outputs enabled		10	ns/V
T_{amb}	Operating free-air temperature range	−40	+85	°C

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DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions

Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT
			Temp = -40°C to +85°C			
			MIN	TYP1	MAX	
V _{IK}	Input clamp voltage	V _{CC} = 2.7V; I _{IK} = -18mA			-1.2	V
V _{OH}	High-level output voltage	V _{CC} = 2.7 to 3.6V; I _{OH} = -100μA	V _{CC} -0.2			V
		V _{CC} = 2.7V; I _{OH} = -6mA	2.4			
		V _{CC} = 3.0V; I _{OH} = -20mA	2.0			
V _{OL}	Low-level output voltage	V _{CC} = 2.7V; I _{OL} = 100μA			0.2	V
		V _{CC} = 2.7V; I _{OL} = 24mA			0.5	
		V _{CC} = 3.0V; I _{OL} = 32mA			0.5	
I _I	Input leakage current	V _{CC} = 0 or 3.6V; V _I = 5.5V			10	μA
		V _{CC} = 3.6V; V _I = V _{CC} or GND			±1	
I _{OFF}	Output off current	V _{CC} = 0V; V _I or V _O = 0 to 4.5V			±100	μA
I _{CCH}	Quiescent supply current	V _{CC} = 3.6V; Outputs High, V _I = GND or V _{CC} , I _O = 0			0.02	mA
I _{CCL}		V _{CC} = 3.6V; Outputs Low, V _I = GND or V _{CC} , I _O = 0		1	2	
ΔI _{CC}	Additional supply current per input pin ²	V _{CC} = 3V to 3.6V; One input at V _{CC} -0.6V, Other inputs at V _{CC} or GND			0.2	μA
C _I	Input capacitance	V _I = 3V or 0		3		pF

NOTES:

1. All typical values are at $V_{CC} = 3.3V$ and $T_{amb} = 25^\circ C$.
2. This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND.

AC CHARACTERISTICSGND = 0V; $t_R = t_F = 2.5ns$; $C_L = 50pF$; $R_L = 500\Omega$; $T_{amb} = -40^\circ C$ to $+85^\circ C$.

SYMBOL	PARAMETER	WAVEFORM	LIMITS				UNIT
			$V_{CC} = 3.3V \pm 0.3V$			$V_{CC} = 2.7V$	
			MIN	TYP ¹	MAX	MAX	
t_{PLH} t_{PHL}	Propagation delay An or Bn to Yn (other input Low)	1	1.0 1.0	3.0 3.5	4.2 5.1	5.3 5.6	ns
t_{PLH} t_{PHL}	Propagation delay An or Bn to Yn (other input High)	2	1.0 1.0	3.4 3.1	5.2 4.2	6.3 4.4	ns

NOTE:

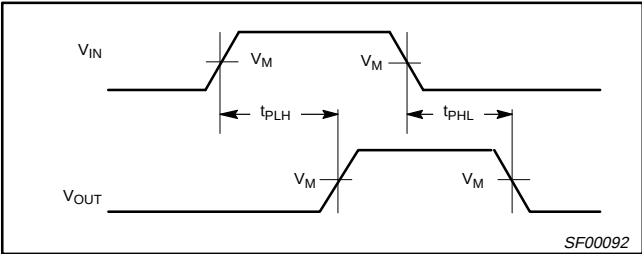
1. All typical values are at $V_{CC} = 3.3V$ and $T_{amb} = 25^\circ C$.

3.3V Quad 2-input exclusive-OR gate

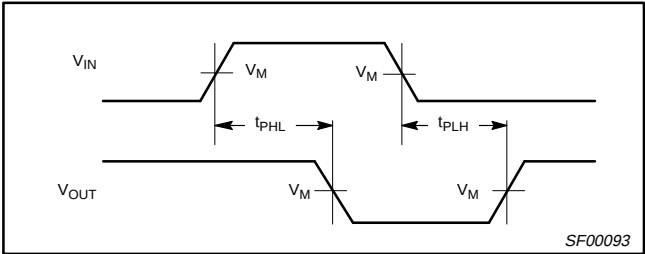
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AC WAVEFORMS

$V_M = 1.5V$, $V_{IN} = GND$ to $2.7V$

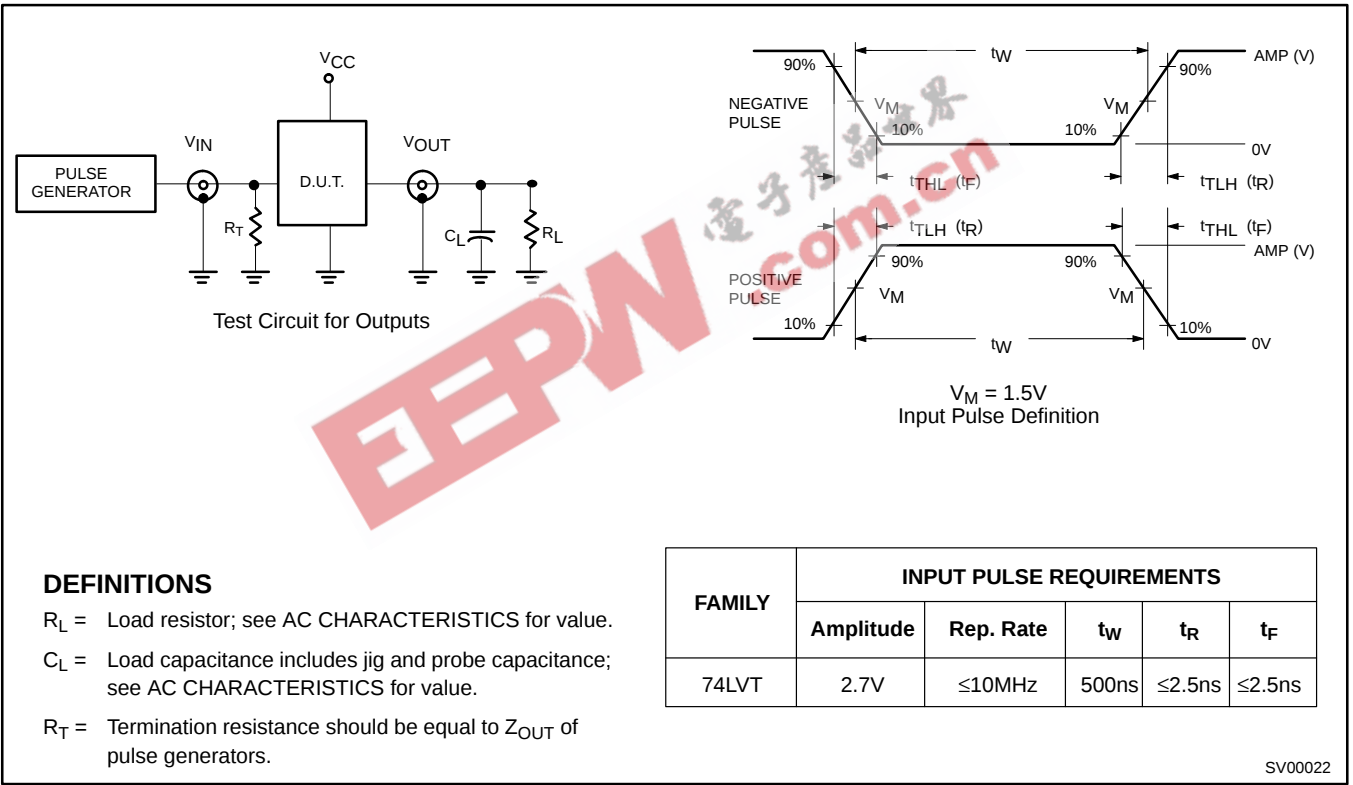


Waveform 1. Propagation Delay for Non-Inverting Outputs



Waveform 2. Propagation Delay for Inverting Outputs

TEST CIRCUIT AND WAVEFORMS

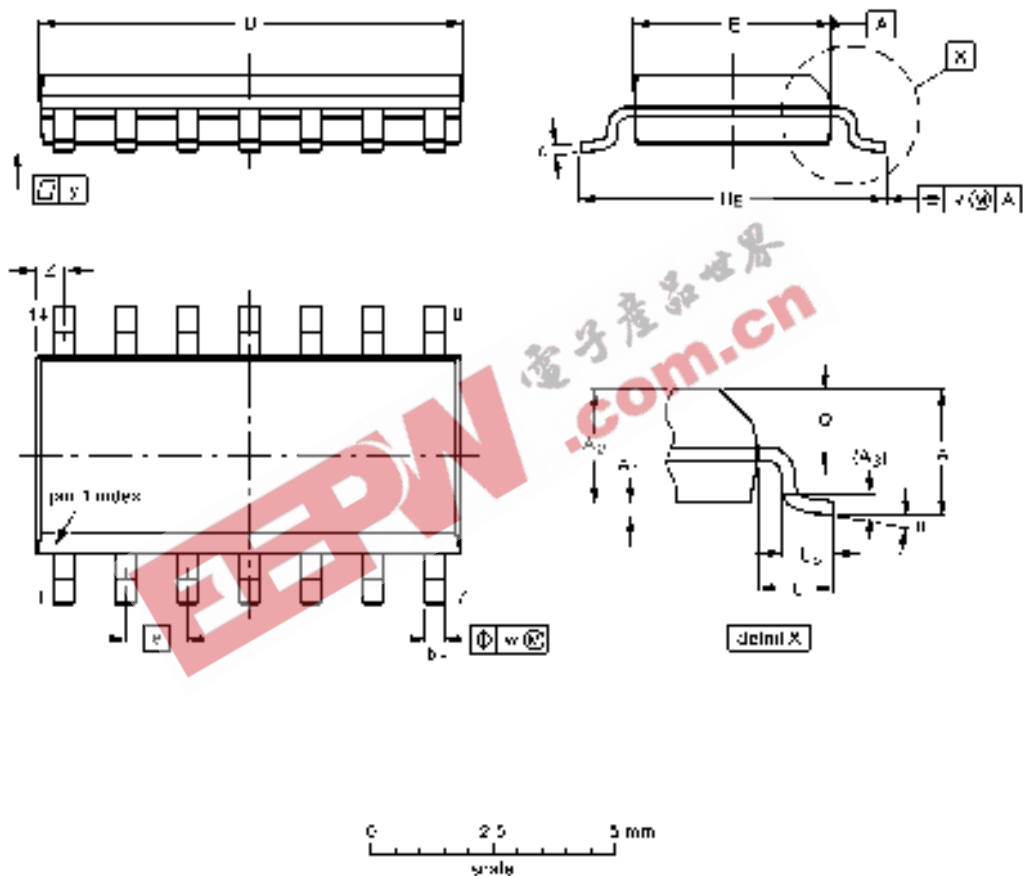


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SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A _{max.}	A ₁	A ₂	A ₃	b _p	e	D ⁽¹⁾	E ⁽¹⁾	F	H _E	L	L _p	Q	v	w	y	Z ⁽¹⁾	r
mm	1.75	0.25 0.10	1.45 1.25	0.20	0.45 0.30	0.25 0.19	8.75 8.50	4.0 3.8	1.27	5.2 5.0	1.65	1.0 0.8	0.7 0.6	0.25	0.25	0.1	0.7 0.3	B ⁽²⁾ D ⁽²⁾
inches	0.069	0.0098 0.0039	0.057 0.049	0.008	0.018 0.014	0.0098 0.0075	0.34 0.34	0.16 0.15	0.050	0.24 0.23	0.064	0.039 0.0316	0.028 0.024	0.01	0.01	0.004	0.028 0.012	

Note

1 Plastic or metal protrusions of 0.15 mm maximum per side are not included

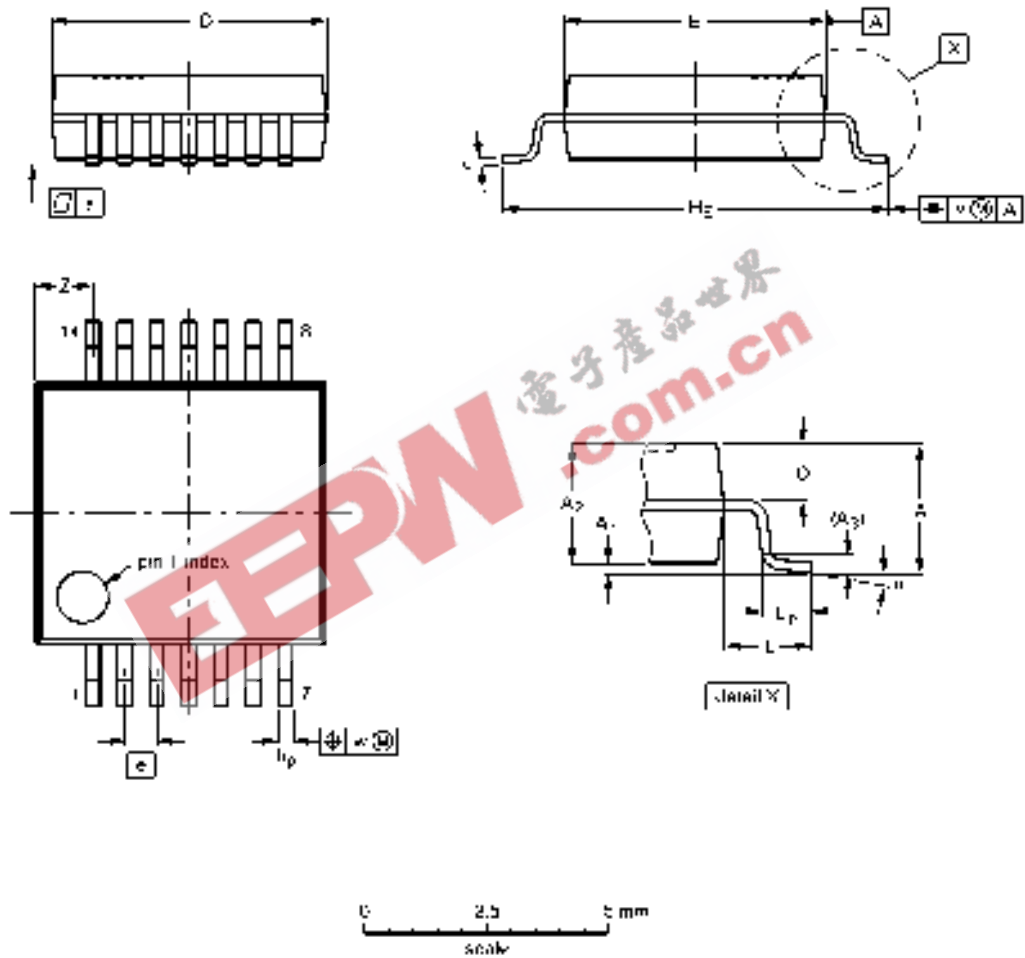
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT108-1	076E065	MS-012AB				91-08-19 95-01-23

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SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	Ø (M)	Ø (I)	e	H _E	L	L _p	Q	y	w	y	Z (M)	z
mm	2.0	0.21 0.25	1.80 1.65	0.30	0.08 0.25	0.20 0.09	6.4 6.0	6.4 5.2	0.65	7.3 7.6	1.25	1.00 0.62	0.9 0.7	0.2	0.12	0.1	1.4 0.9	0° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

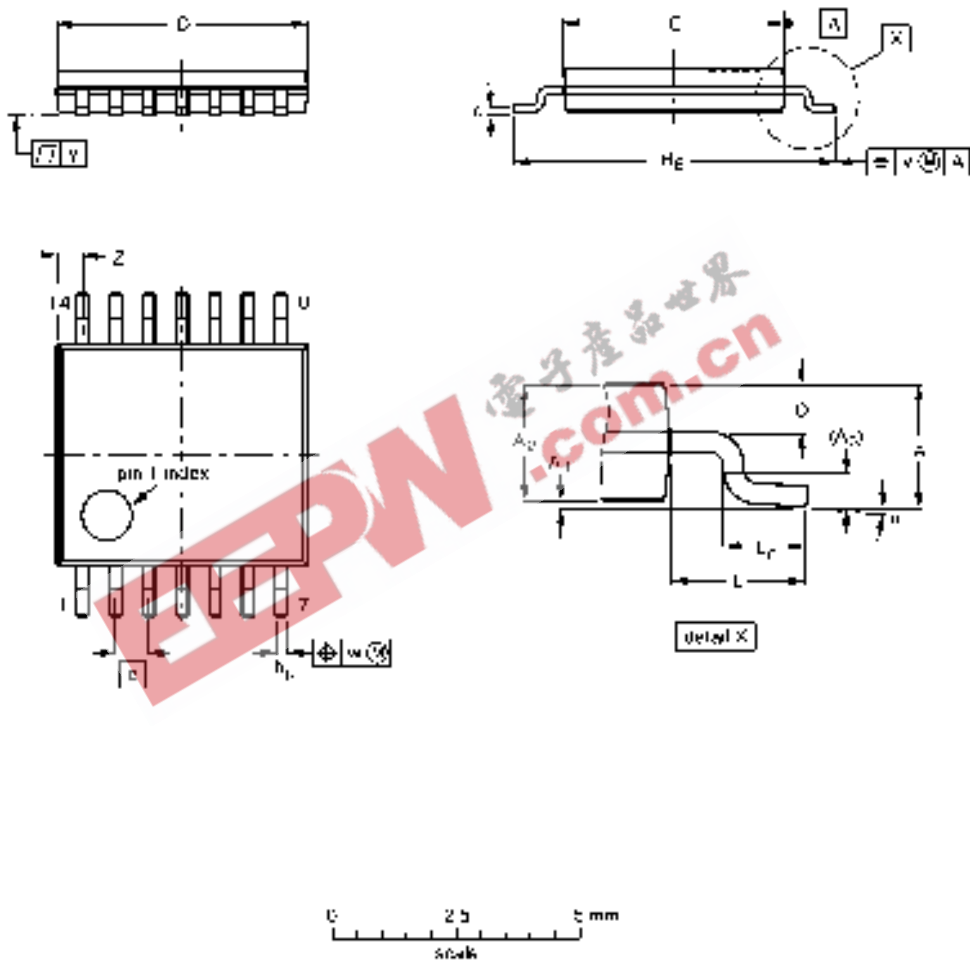
OUTLINE VERSION	REFERENCES			EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ		
SOT337-1		MO-150AB			95-85-94 Ver. 01-19

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TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max	A ₁	A ₂	A ₃	b _p	c	D (M)	E (2)	e	H _E	L	L _p	Q	v	w	y	Z (1)	W
mm	1.10	0.15 0.75	0.05 0.60	0.25	0.50 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.95	6.6 6.2	1.0	0.75 0.53	0.4 0.3	0.2	0.13	0.1	0.72 0.38	0° 0°

Notes

- 1 Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2 Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT402-1		MO-150				94-07-12 95-11-01

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NOTES

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DEFINITIONS

Data Sheet Identification	Product Status	Definition
<i>Objective Specification</i>	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.
<i>Preliminary Specification</i>	Preproduction Product	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
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